

Notes : 1. Alumina=0.4*0.3*0.024in.99.5% alumina
2. " Fully ROHS Compliant ", "100% Sn plating (Pb-free)"

Rve.A_Aug,2017

ELECTRICAL CHARACTERISTICS (@TA=25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage(1) ($I_C = -10 \text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	-60	-	Vdc
Collector-Base Breakdown Voltage ($I_C = -10 \mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	-60	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = -10 \mu\text{A}$, $I_C = 0$)	$V_{(BR)EBO}$	-5.0	-	Vdc
Collector Cutoff Current ($V_{CE} = -30 \text{ Vdc}$, $V_{BE(off)} = -5.0 \text{ Vdc}$)	I_{CEX}	-	-50	nAdc
Collector Cutoff Current ($V_{CB} = -50 \text{ Vdc}$, $I_E = 0$) ($V_{CB} = -50 \text{ Vdc}$, $I_E = 0$, $T_A = 125^\circ\text{C}$)	I_{CBO}	-	-0.02 -20	 uAdc
Base Current ($V_{CE} = -30 \text{ Vdc}$, $V_{EB(off)} = -0.5 \text{ Vdc}$)	I_B	-	-50	nAdc

ON CHARACTERISTICS

DC Current Gain ($I_C = -0.1 \text{ mA}$, $V_{CE} = -10 \text{ Vdc}$) ($I_C = -1.0 \text{ mA}$, $V_{CE} = -10 \text{ Vdc}$) ($I_C = -10 \text{ mA}$, $V_{CE} = -10 \text{ Vdc}$) ($I_C = -150 \text{ mA}$, $V_{CE} = -10 \text{ Vdc}$)(1) ($I_C = -500 \text{ mA}$, $V_{CE} = -10 \text{ Vdc}$)(1)	h_{FE}	75 100 100 100 50	- - - 300 -	-
Collector-Emitter Saturation Voltage (1) ($I_C = -150 \text{ mA}$, $I_B = -15 \text{ mA}$) ($I_C = -500 \text{ mA}$, $I_B = -50 \text{ mA}$)	$V_{CE(sat)}$	- -	-0.4 -1.6	Vdc
Base-Emitter Saturation Voltage (1) ($I_C = -150 \text{ mA}$, $I_B = -15 \text{ mA}$) ($I_C = -500 \text{ mA}$, $I_B = -50 \text{ mA}$)	$V_{BE(sat)}$	- -	-1.3 -2.6	Vdc

SMALL-SIGNAL CHARACTERISTICS

Current-Gain-Bandwidth Product (1)(2) ($I_C = -50 \text{ mA}$, $V_{CE} = -20 \text{ Vdc}$, $f = 100 \text{ MHz}$)	f_T	200	-	MHz
Output Capacitance ($V_{CB} = -10 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	C_{obo}	-	8.0	pF
Input Impedance ($V_{EB} = -2.0 \text{ Vdc}$, $I_C = 0$, $f = 1.0 \text{ MHz}$)	C_{ibo}	-	30	pF

SWITCHING CHARACTERISTICS

Turn-On Time	$(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mA}, I_{B1} = -15 \text{ mA})$	t_{on}	-	45	ns
Delay Time		t_d	-	10	
Rise Time		t_r	-	40	
Turn-Off Time	$(V_{CC} = -6.0 \text{ Vdc}, I_C = -150 \text{ mA}, I_{B1} = I_{B2} = -15 \text{ mA})$	t_{off}	-	100	ns
Storage Time		t_s	-	80	
Fall Time		t_f	-	30	

NOTES : 1. Pulse Test: Pulse Width $\leq 300 \text{ ms}$, Duty Cycle $\leq 2.0\%$

2. f_T is defined as the frequency at which $|h_{FE}|$ extrapolates to unity

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